## HD14021B

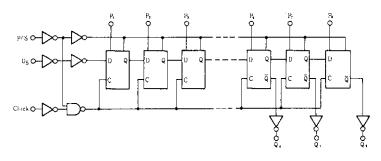
#### 8-bit Static Shift Register

The HD14021B 8-bit Static shift register finds primary use in parallel-to serial data conversion, asynchronous parallel input, serial output data queueing; and other general purpose register applications requiring low power and/or high noise immunity.

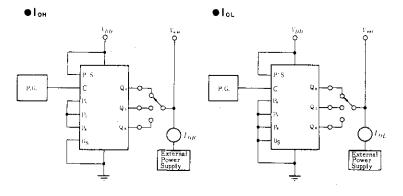
#### **FEATURES**

- Quiescent Current = 5nA/pkg typ. @5V
- Asynchronous Parallel Input/Serial Output
- Full Static Operation from DC to 7MHz
- Supply Voltage Range = 3 to 18V
- Capable of Driving One Low-power Schottky TTL Load Over the Rated Temperature Range

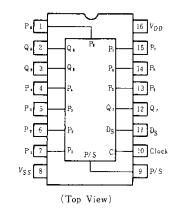
#### **■LOGIC DIAGRAM**



#### ■ DC CHARACTERISTIC TEST CIRCUIT



#### **■ PIN ARRANGEMENT**



#### TRUTH TABLE

#### Serial Operation

	t	Clock	D,	P/S			
	n		0	0			
	n + 1		1	0			
	n + 2		0	0			
•	n + 3		1	0			
		~	×	0			

Q,	Q <sub>7</sub>	Q,		
t = n + 6	t = n + 7	t = n + 8		
0	?	?		
1	. 0	?		
0	1	0		
1	0	1		
Q,	Q <sub>7</sub>	Q,		

#### ● Parallel Operation

Clock	D,	P/S	Dm	Qm*		
	×	1	0	0		
\	×	1	1	1		

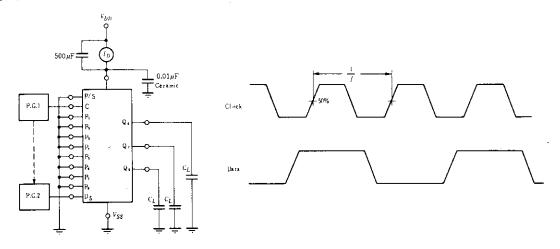
注) \*: Qs, Q7, & Qs are available externally ×: Don't Care

#### ■ ELECTRICAL CHARACTERISTICS

Characteristic	C		Test Conditions	-4	၁၀		25℃		85°	c ;	Unit
Characteristic	Symbol	$V_{aa}(V)$	5.0	min	max	min	typ	max	min	max	Onit
			<u>.</u>		0.05	-	0	0.05	_	0.05	v
	Vol	10		_	0.05	-	0	0.05	_ }	0.05	
O V.N		15			0.05	-	0	0.05	-	0.05	
Output Voltage		5.0		4.95	_	4.95	5.0	_	4.95		v
	Von	10	$V_{in}=0$ or $V_{DD}$	9.95		9.95	10		9,95	_	
		15		14.95		14.95	15		14.95		
14		5.0	$V_{out} = 4.5 \text{ or } 0.5 \text{V}$	-	1.5	-	2.25	1.5	_	1.5	v
	$V_{IL}$	10	$V_{out} = 9.0 \text{ or } 1.0\text{V}$		3.0		4.50	3.0		3.0	
T6 37-14.		15	V <sub>**</sub> , = 13.5 or 1.5V	_	4.0	_	6.75	4.0	_	4.0	
Input Voltage	$ \begin{array}{ c c c c c c c c } \hline Symbol & V_{DD}(V) \\ \hline V_{OL} & 10 & V_{DD} & 0r & 0 \\ \hline & 5.0 & & & & & & & & & & & & & & & & & & &$	5.0	$V_{***} = 0.5 \text{ or } 4.5 \text{V}$	3.5	_	3.5	2.75		3.5	_	
			v								
		15	$V_{\rm out} = 1.5 \text{ or } 13.5 \text{V}$	11.0	_	11.0	8.25	-	11.0	_	
	Іон	5.0	$V_{OH}=2.5V$	-1.0	_	-0.8	-1.7	_	-0.6		mA
		5.0	$V_{OH} = 4.6 \text{V}$	-0.2	_	-0.16	-0.36	_	-0.12		
		10	$V_{OH} = 9.5V$	-0.5		-0.4	-0.9	_	-0.3	-	
Output Drive Current		15	$V_{OH} = 13.5 \text{V}$	-1.4	_	-1.2	-3.5		-1.0	- 1	
		5.0	$V_{oL} = 0.4V$	0.52		0.44	0.88	_	0.36	_	mA
	IoL	10	$V_{ol} = 0.5 \text{V}$	1.3	_	1.1	2.25	_	0.9		
		15	$V_{oL} = 1.5V$	3.6	_	3.0	8.8	_	2.4	-	
Input Current	I in	15	!	_	±0.3	_	±0.00001	$\pm 0.3$	_	±1.0	μA
Input Capacitance	Cin		V., = 0	_	_	_	5.0	7.5	i –	_	pF
		5.0		-	20	_	0.005	20	_	150	$\top$
Quiescent Current	Current $I_{in}$ 15 $ \pm 0.3$ $ \pm 0.00001$ $\pm 0.3$ Capacitance $C_{in}$ $V_{in} = 0$ $         -$	-	300	μA							
		15	er Package	_	80	_	0.015	80	_	600	1
-	ì	5.0	Dynamic $+I_{DD}$ ,	_	-	i –	0.76	_	_	_	μA
Total Supply Current*	$I_T$	10	1 .		† <u> </u>	_	1.51	_		_	
• • •		_	1 2			-	<b>†</b>		•	1	1

<sup>\*</sup> To calculate total supply current at frequency other than IkHz.

## ■POWER DISSIPATION TEST CIRCUIT AND WAVEFORM

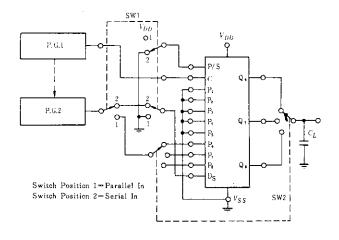


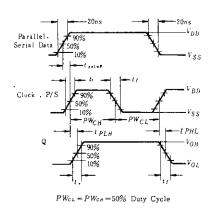
 $<sup>@</sup>V_{0D} = 5.0 \text{V} \quad I_{T} = (0.75 \, \mu\text{A/kHz}) \\ f + I_{DD}, \quad @V_{0D} = 10 \text{V} \quad I_{T} = (1.50 \, \mu\text{A/kHz}) \\ f + I_{DD}, \quad @V_{DD} = 15 \text{V} \quad I_{T} = (2.25 \, \mu\text{A/kHz}) \\ f + I_{DD}, \quad &I_{D$ 

## **ESWITCHING CHARACTERISTICS** $(C_L = 50 \text{pF}, Ta = 25^{\circ}\text{C})$

Characteristic	Symbol	$V_{DD}(V)$	min	typ	max	Unit
:		5.0	_	180	400	ns
Output Rise Time	t. [	10		90	200	
		15	_	65	160	
		5.0		100	200	
Output Fall Time	$t_f$	10		50	100	ns
		15		37	80	1
		5.0		400	1000	ns .
Propagation Delay Time	tplH,	10	-	170	400	
	t <sub>PHL</sub>	15	<u> </u>	115	265	
		5.0	500	150		ns
Clock Pulse Width	$PW_c$	10	200	75	_	
		15	150	40		
	$f_{c}$	5.0		3.0	1.0	MHz
Clock Frequency		10		6.0	2.5	
		15		8.0	3.0	
		5.0	500	150		ns
Parallel/Serial Control Pulse Width	PW(P/S)	10	200	75		
		15	150	40	_	
		5.0	500	150	_	i
Setup Time	tsetup	10	100	50	_	ns
		15	-80	30		1
		5.0	_	-	15	
Input Clock Rise Time	t	10			15	ns ns
		15	_	—	15	:

### ■ SWITCHING TIME TEST CIRCUIT





Unit: mm 19.20 20.00 Max 16 7.40 Max 6.30 1.3 1.11 Max 7.62 5.06 Max 2.54 Min 0.51 Min  $0.25^{+0.13}_{-0.05}$  $0.48 \pm 0.10$  $2.54\pm0.25$  $0^{\circ} - 15^{\circ}$ Hitachi Code DP-16 **JEDEC** Conforms EIAJ Conforms Weight (reference value) 1.07 g

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